# Analog Switch, Dual SPDT, Ultra Low 0.35 $\Omega$

The NLAS5223B is an advanced CMOS analog switch fabricated in Sub–micron silicon gate CMOS technology. The device is a dual Independent Single Pole Double Throw (SPDT) switch featuring Ultra–Low  $R_{ON}$  of 0.35  $\Omega$ , at  $V_{CC} = 4.3$  V.

The part also features guaranteed Break Before Make (BBM) switching, assuring the switches never short the driver.

#### Features

- Ultra–Low R<sub>ON</sub>, 0.35  $\Omega$  (typ) at V<sub>CC</sub> = 4.3 V
- NLAS5223B Interfaces with 2.8 V Chipset
- NLAS5223BL Interfaces with 1.8 V Chipset
- Single Supply Operation from 1.65–4.5 V
- Full 0–V<sub>CC</sub> Signal Handling Capability
- High Off-Channel Isolation
- Low Standby Current, < 50 nA
- Low Distortion
- $R_{ON}$  Flatness of 0.15  $\Omega$
- High Continuous Current Capability
  ±320 mA Through Each Switch
- Large Current Clamping Diodes at Analog Inputs
  ±100 mA Continuous Current Capability
- Package:
  - 1.4 x 1.8 x 0.75 mm WQFN10 Pb-Free
  - 1.4 x 1.8 x 0.55 mm UQFN10 Pb–Free
- These are Pb–Free Devices

#### Applications

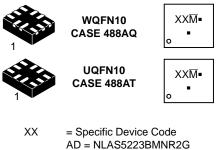
- Cell Phone Audio Block
- Speaker and Earphone Switching
- Ring–Tone Chip/Amplifier Switching
- Modems



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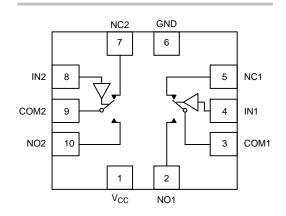
#### MARKING DIAGRAM



	AD = NLASSZZSDIVINKZG
	AE = NLAS5223BLMNR2G
	AP = NLAS5223BMUR2G
Μ	= Date Code/Assembly Location

= Pb-Free Device

(Note: Microdot may be in either location)



#### FUNCTION TABLE

IN 1, 2	NO 1, 2	NC 1, 2
0	OFF	ON
1	ON	OFF

#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 9 of this data sheet.

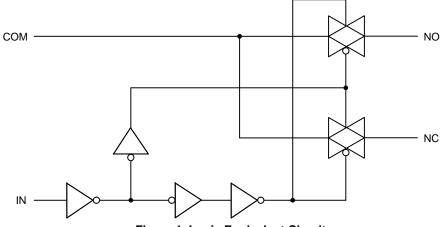


Figure 1. Logic Equivalent Circuit

#### **PIN DESCRIPTION**

QFN PIN #	Symbol	Name and Function
2, 5, 7, 10	NC1 to NC2, NO1 to NO2	Independent Channels
4, 8	IN1 and IN2	Controls
3, 9	COM1 and COM2	Common Channels
6	GND	Ground (V)
1	V <sub>CC</sub>	Positive Supply Voltage

#### **MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	Positive DC Supply Voltage	-0.5 to +5.5	V
V <sub>IS</sub>	Analog Input Voltage (V <sub>NO</sub> , V <sub>NC</sub> , or V <sub>COM</sub> )	$-0.5 \le V_{IS} \le V_{CC} + 0.5$	V
V <sub>IN</sub>	Digital Select Input Voltage	$-0.5 \le V_{IN} \le +5.5$	V
I <sub>anl1</sub>	Continuous DC Current from COM to NC/NO	±320	mA
I <sub>anl-pk1</sub>	Peak Current from COM to NC/NO, 10% Duty Cycle, 100 ms = t <sub>ON</sub> (Note 1)	±600	mA
I <sub>anl-pk2</sub>	Instantaneous Peak Current from COM to NC/NO, 10% Duty Cycle, $t_{\text{ON}}$ < 1 $\mu s$	±850	mA
I <sub>cImp</sub>	Continuous DC Current into COM/NO/NC with Respect to $V_{CC}$ or GND	±100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. 1. Defined as 10% ON, 90% OFF Duty Cycle.

#### **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter	Min	Max	Unit
V <sub>CC</sub>	DC Supply Voltage	1.65	4.5	V
V <sub>IN</sub>	Digital Select Input Voltage (OVT) Overvoltage Tolerance	GND	4.5	V
V <sub>IS</sub>	Analog Input Voltage (NC, NO, COM)	GND	V <sub>CC</sub>	V
T <sub>A</sub>	Operating Temperature Range	-40	+85	°C
t <sub>r</sub> , t <sub>f</sub>	Input Rise or Fall Time, SELECT $V_{CC} = 1.6 V - 2.7 V$ $V_{CC} = 3.0 V - 4.5 V$		20 10	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

#### NLAS5223B DC CHARACTERISTICS - DIGITAL SECTION (Voltages Referenced to GND)

				Guaranteed Limit		
Symbol	Parameter	Condition	V <sub>cc</sub>	25°C	–40°C to +85°C	Unit
V <sub>IH</sub>	Minimum High-Level Input Voltage, Select Inputs		3.0 4.3	1.4 2.0	1.4 2.0	V
V <sub>IL</sub>	Maximum Low–Level Input Voltage, Select Inputs		3.0 4.3	0.7 0.8	0.7 0.8	V
I <sub>IN</sub>	Maximum Input Leakage Current, Select Inputs	$V_{IN} = V_{CC}$ or GND	4.3	±0.1	±1.0	μΑ
I <sub>OFF</sub>	Power Off Leakage Current	$V_{IN} = V_{CC}$ or GND	0	±0.5	±2.0	μΑ
I <sub>CC</sub>	Maximum Quiescent Supply Current (Note 2)	Select and $V_{IS} = V_{CC}$ or GND	1.65 to 4.5	±1.0	±2.0	μΑ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Guaranteed by design. Resistance measurements do not include test circuit or package resistance.

#### NLAS5223B DC ELECTRICAL CHARACTERISTICS – ANALOG SECTION

				Gua	n Limit	-		
				25°C			–40°C to +85°C	
Symbol	Parameter	Condition	v <sub>cc</sub>	Min	Max	Min	Max	Unit
R <sub>ON</sub>	NC/NO On–Resistance (Note 3)		3.0 4.3		0.4 0.35		0.5 0.4	Ω
R <sub>FLAT</sub>	NC/NO On–Resistance Flatness (Notes 3 and 4)	$I_{COM} = 100 \text{ mA}$ $V_{IS} = 0 \text{ to } V_{CC}$	3.0 4.3		0.16 0.11		0.20 0.14	Ω
$\Delta R_{ON}$	On–Resistance Match Between Channels (Notes 3 and 5)	$V_{IS} = 1.5 V; \\ I_{COM} = 100 \text{ mA} \\ V_{IS} = 2.2 V; \\ I_{COM} = 100 \text{ mA} \end{cases}$	3.0 4.3		0.05 0.05		0.05 0.05	Ω
I <sub>NC(OFF)</sub> I <sub>NO(OFF)</sub>	NC or NO Off Leakage Current (Note 3)	$ \begin{array}{l} V_{IN} = V_{IL} \text{ or } V_{IH} \\ V_{NO} \text{ or } V_{NC} = 0.3 \ V \\ V_{COM} = \ 4.0 \ V \end{array} $	4.3	-5.0	5.0	-50	50	nA
I <sub>COM(ON)</sub>	COM ON Leakage Current (Note 3)	$\label{eq:VIN} \begin{array}{l} V_{IN} = V_{IL} \mbox{ or } V_{IH} \\ V_{NO} \mbox{ 0.3 V or 4.0 V with} \\ V_{NC} \mbox{ floating or} \\ V_{NC} \mbox{ 0.3 V or 4.0 V with} \\ V_{NO} \mbox{ floating} \\ V_{COM} = \mbox{ 0.3 V or 4.0 V} \end{array}$	4.3	-10	10	-100	100	nA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

3. Guaranteed by design. Resistance measurements do not include test circuit or package resistance.

4. Flatness is defined as the difference between the maximum and minimum value of On-resistance as measured over the specified analog signal ranges.

5.  $\Delta \tilde{R}_{ON} = \tilde{R}_{ON(MAX)} - \tilde{R}_{ON(MIN)}$  between NC1 and NC2 or between NO1 and NO2.

#### NLAS5223BL DC CHARACTERISTICS - DIGITAL SECTION (Voltages Referenced to GND)

				Guaranteed Limit		
Symbol	Parameter	Condition	V <sub>cc</sub>	25°C	–40°C to +85°C	Unit
V <sub>IH</sub>	Minimum High-Level Input Voltage, Select Inputs		3.0 4.3	1.3 1.6	1.3 1.6	V
V <sub>IL</sub>	Maximum Low–Level Input Voltage, Select Inputs		3.0 4.3	0.5 0.6	0.5 0.6	V
I <sub>IN</sub>	Maximum Input Leakage Current, Select Inputs	$V_{IN} = 4.5 V \text{ or GND}$	4.3	±0.1	±1.0	μΑ
I <sub>OFF</sub>	Power Off Leakage Current	V <sub>IN</sub> = 4.5 V or GND	0	±0.5	±2.0	μΑ
I <sub>CC</sub>	Maximum Quiescent Supply Current (Note 6)	Select and $V_{IS} = V_{CC}$ or GND	1.65 to 4.5	±1.0	±2.0	μΑ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

6. Guaranteed by design. Resistance measurements do not include test circuit or package resistance.

#### NLAS5223BL DC ELECTRICAL CHARACTERISTICS – ANALOG SECTION

				Gua				
				25	i°C	-40°C t	o +85°C	1
Symbol	Parameter	Condition	V <sub>CC</sub>	Min	Мах	Min	Max	Unit
R <sub>ON</sub>	NC/NO On–Resistance (Note 7)		3.0 4.3		0.4 0.35		0.5 0.4	Ω
R <sub>FLAT</sub>	NC/NO On–Resistance Flatness (Notes 7 and 8)	$I_{COM} = 100 \text{ mA}$ $V_{IS} = 0 \text{ to } V_{CC}$	3.0 4.3		0.16 0.11		0.20 0.14	Ω
$\Delta R_{ON}$	On–Resistance Match Between Channels (Notes 7 and 9)	$V_{IS} = 1.5 V;$ $I_{COM} = 100 \text{ mA}$ $V_{IS} = 2.2 V;$ $I_{COM} = 100 \text{ mA}$	3.0 4.3		0.05 0.05		0.05 0.05	Ω
I <sub>NC(OFF)</sub> I <sub>NO(OFF)</sub>	NC or NO Off Leakage Current (Note 7)	$ \begin{array}{l} V_{IN} = V_{IL} \text{ or } V_{IH} \\ V_{NO} \text{ or } V_{NC} = 0.3 \ V \\ V_{COM} = \ 4.0 \ V \end{array} $	4.3	-10	10	-100	100	nA
I <sub>COM(ON)</sub>	COM ON Leakage Current (Note 7)		4.3	-10	10	-100	100	nA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

7. Guaranteed by design. Resistance measurements do not include test circuit or package resistance.

8. Flatness is defined as the difference between the maximum and minimum value of On-resistance as measured over the specified analog signal ranges.

9.  $\Delta R_{ON} = R_{ON(MAX)} - R_{ON(MIN)}$  between NC1 and NC2 or between NO1 and NO2.

#### **AC ELECTRICAL CHARACTERISTICS** (Input $t_r = t_f = 3.0$ ns)

					Guaranteed M		aximum L					
			V V	V	V.	V <sub>IS</sub> 25		25°C		–40°C to	o +85°C	
Symbol	Parameter	Test Conditions	V <sub>CC</sub> (V)	(V)	Min	Тур*	Max	Min	Max	Unit		
t <sub>ON</sub>	Turn–On Time	$R_L = 50 \Omega$ , $C_L = 35 pF$ (Figures 3 and 4)	2.3 - 4.5	1.5			50		60	ns		
tOFF	Turn–Off Time	$R_L = 50 \Omega$ , $C_L = 35 pF$ (Figures 3 and 4)	2.3 - 4.5	1.5			30		40	ns		
t <sub>BBM</sub>	Minimum Break–Before–Make Time	$V_{IS} = 3.0$ $R_L = 50 \ \Omega, \ C_L = 35 \ pF$ (Figure 2)	3.0	1.5	2	15				ns		

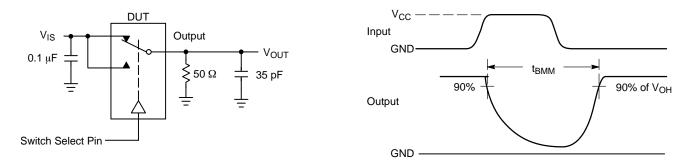
		Typical @ 25, V <sub>CC</sub> = 3.6 V	
C <sub>IN</sub>	Control Pin Input Capacitance	3.5	pF
C <sub>NO/NC</sub>	NO, NC Port Capacitance	60	pF
C <sub>COM</sub>	COM Port Capacitance When Switch is Enabled	200	pF

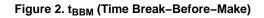
\*Typical Characteristics are at 25°C.

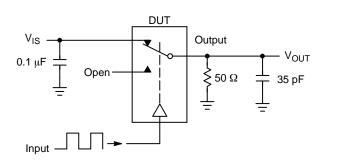
#### ADDITIONAL APPLICATION CHARACTERISTICS (Voltages Referenced to GND Unless Noted)

			V <sub>cc</sub>	25°C	
Symbol	Parameter	Condition	(V)	Typical	Unit
BW	Maximum On–Channel –3 dB Bandwidth or Minimum Frequency Response	$V_{\text{IN}}$ centered between $V_{\text{CC}}$ and GND (Figure 5)	1.65 – 4.5	19	MHz
V <sub>ONL</sub>	Maximum Feed-through On Loss	$V_{IN} = 0 \text{ dBm } @ 100 \text{ kHz to 50 MHz}$ $V_{IN}$ centered between $V_{CC}$ and GND (Figure 5)	1.65 – 4.5	-0.06	dB
V <sub>ISO</sub>	Off-Channel Isolation	f = 100 kHz; $V_{IS}$ = 1 V RMS; $C_L$ = 5.0 pF $V_{IN}$ centered between $V_{CC}$ and GND (Figure 5)	1.65 – 4.5	-68	dB
Q	Charge Injection Select Input to Common I/O	$V_{IN} = V_{CC to} \text{ GND}, R_{IS} = 0 \Omega, C_L = 1.0 \text{ nF}$ Q = C <sub>L</sub> x DV <sub>OUT</sub> (Figure 6)	1.65 – 4.5	38	рС
THD	Total Harmonic Distortion THD + Noise	$F_{IS}$ = 20 Hz to 20 kHz, $R_L$ = $R_{gen}$ = 600 $\Omega,~C_L$ = 50 pF $V_{IS}$ = 2.0 V RMS	3.0	0.08	%
VCT	Channel-to-Channel Crosstalk	f = 100 kHz; V <sub>IS</sub> = 1.0 V RMS, C <sub>L</sub> = 5.0 pF, R <sub>L</sub> = 50 $\Omega$ V <sub>IN</sub> centered between V <sub>CC</sub> and GND (Figure 5)	1.65 – 4.5	-70	dB

10. Off-Channel Isolation = 20log10 ( $V_{COM}/V_{NO}$ ),  $V_{COM}$  = output,  $V_{NO}$  = input to off switch.







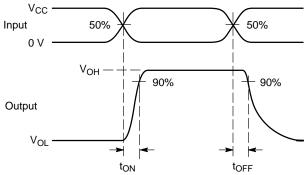
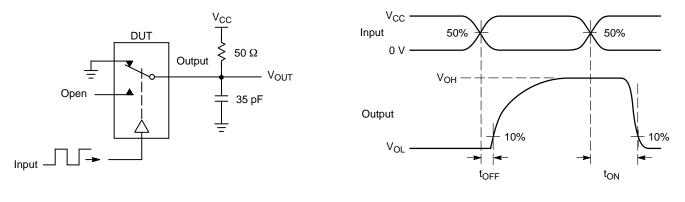
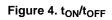
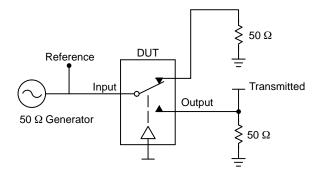


Figure 3. t<sub>ON</sub>/t<sub>OFF</sub>



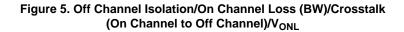




Channel switch control/s test socket is normalized. Off isolation is measured across an off channel. On loss is the bandwidth of an On switch.  $V_{ISO}$ , Bandwidth and  $V_{ONL}$  are independent of the input signal direction.

$$\begin{split} &V_{ISO} = \text{Off Channel Isolation} = 20 \text{ Log} \Big( \frac{V_{OUT}}{V_{IN}} \Big) \text{for } V_{IN} \text{ at } 100 \text{ kHz} \\ &V_{ONL} = \text{On Channel Loss} = 20 \text{ Log} \Big( \frac{V_{OUT}}{V_{IN}} \Big) \text{ for } V_{IN} \text{ at } 100 \text{ kHz} \text{ to } 50 \text{ MHz} \end{split}$$

Bandwidth (BW) = the frequency 3 dB below V<sub>ONL</sub> V<sub>CT</sub> = Use V<sub>ISO</sub> setup and test to all other switch analog input/outputs terminated with 50  $\Omega$ 



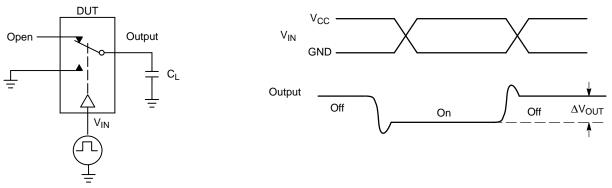
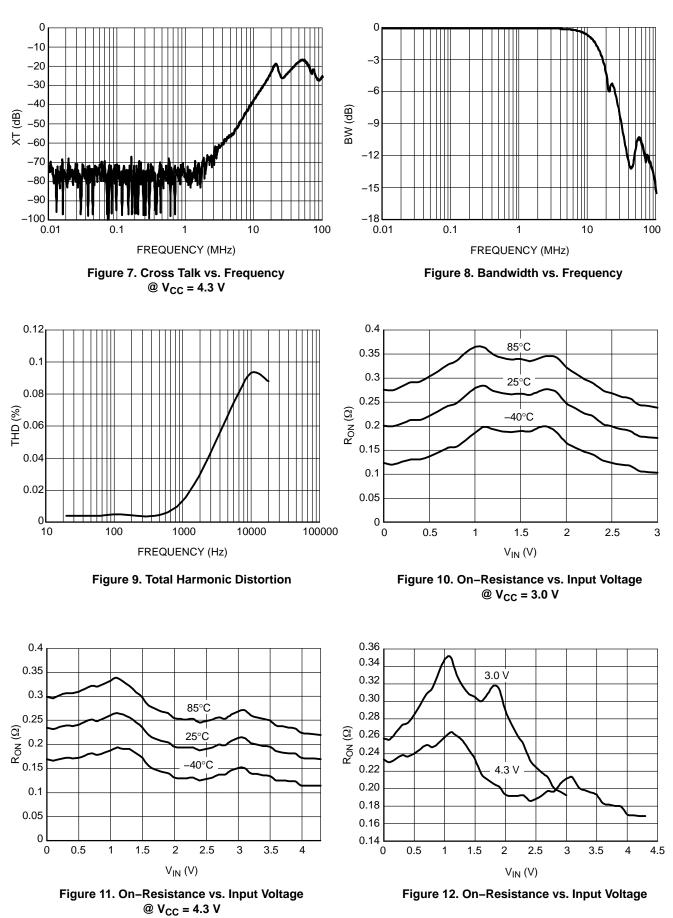


Figure 6. Charge Injection: (Q)

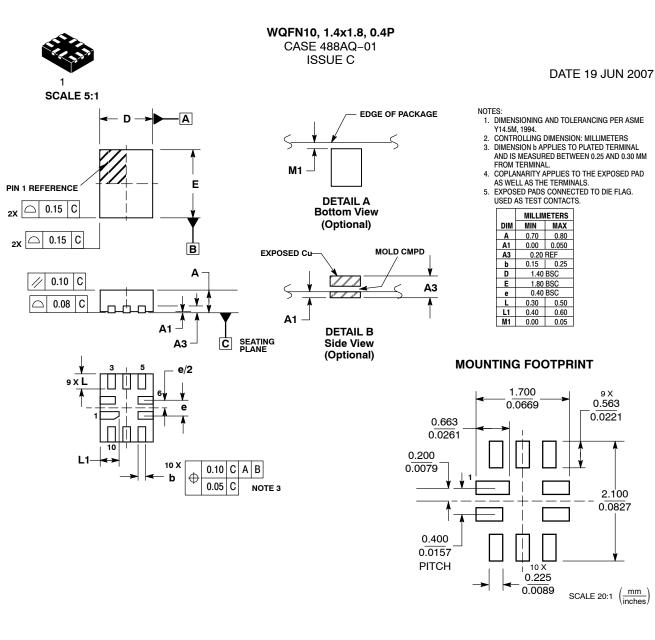


#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>	
NLAS5223BMNR2G	WQFN10 (Pb-Free)	3000 / Tape & Reel	
NLAS5223BLMNR2G	WQFN10 (Pb-Free)	3000 / Tape & Reel	
NLAS5223BMUR2G	UQFN10 (Pb-Free)	3000 / Tape & Reel	

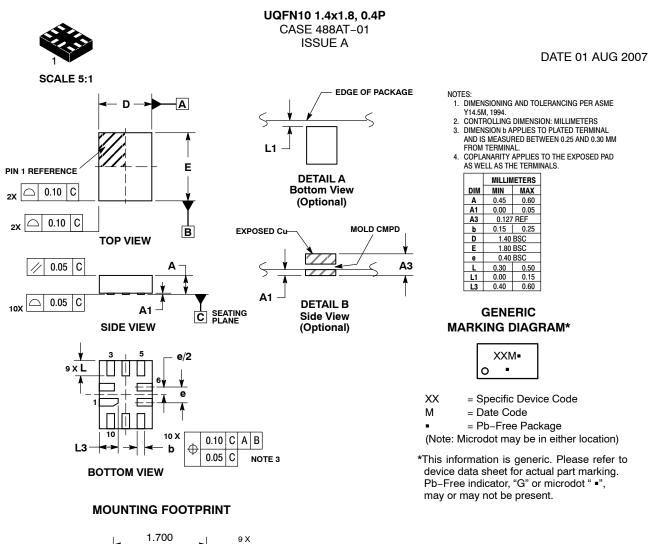
+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

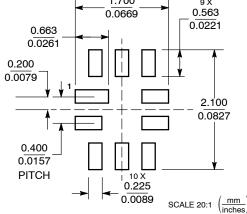




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